

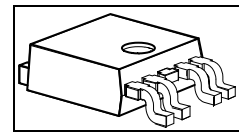
## Smart Power High-Side-Switch One Channel: 1 x 200mΩ

### Features

- Short-circuit protection
- Current limitation
- Overload protection
- Overvoltage protection (including load dump)
- Undervoltage shutdown with autorestart and hysteresis
- Switching inductive loads
- Clamp of negative voltage at output with inductive loads
- Thermal shutdown with restart
- ESD - Protection
- Loss of GND and loss of  $V_{bb}$  protection
- Reverse battery protection with external resistor
- **Improved electromagnetic compatibility (EMC)**

### Product Summary

		BTS 4501D	BTS 4141D	
Overvoltage protection	$V_{bb(AZ)}$	47	47	V
Operating voltage	$V_{bb(on)}$	12...35	12... <b>45</b>	V
On-state resistance	$R_{ON}$	200	200	mΩ



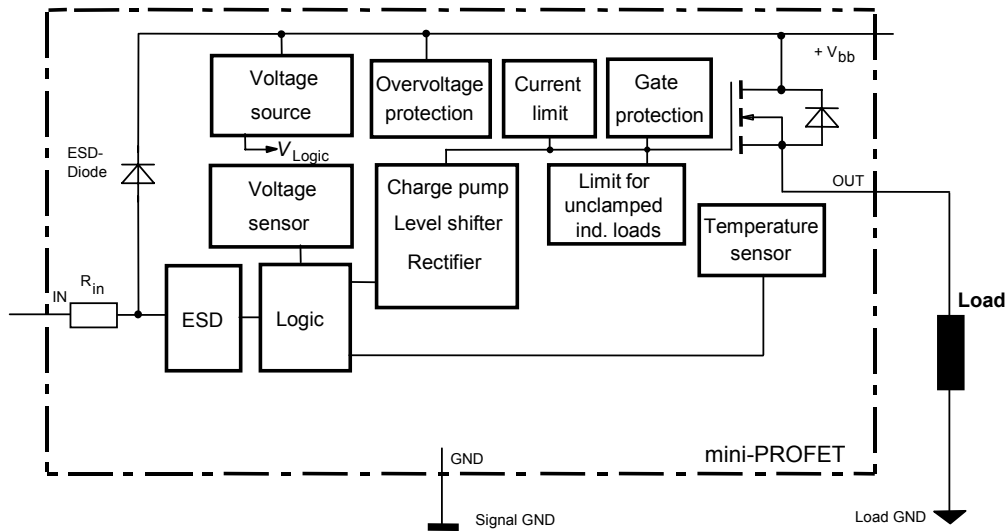
### Application

- All types of resistive, inductive and capacitive loads
- Current controlled power switch for 12 V and 24 V DC applications
- Replaces electromechanical relays and discrete circuits

### General Description

N channel vertical power MOSFET with charge pump ground referenced CMOS compatible input, monolithically integrated in Smart SIPMOS technology. Fully protected by embedded protection functions.

**Block Diagram**



Pin	Symbol	Function
1	OUT	Output to the load
2	NC	not connected
3	Vbb	connected with TAB
4	GND	Logic ground
5	IN	Input, activates the power switch in case of logic high signal
TAB	Vbb	Positive power supply voltage



### Electrical Characteristics

#### BTS 4501D                      BTS 4141D

Parameter and Conditions	Symbol	Values			Unit		
		at $T_j = 25\text{ }^\circ\text{C}$ , $V_{bb} = 24\text{ V}$			at $T_j = -40\dots125\text{ }^\circ\text{C}$ , $V_{bb} = 15\dots30\text{ V}$		
		min	typ	max	min	typ	max

### Load Switching Capabilities and Characteristics

On-state resistance $T_j = 25\text{ }^\circ\text{C}$ , $I_L = 0,5\text{ A}$ $T_j = 125\text{ }^\circ\text{C}$	$R_{ON}$	--	0,16	0,2 0,38	--	0,15 0,27 0,32	0,2 0,32	$\Omega$
Nominal load current Device on PCB <sup>1)</sup>	$I_{L(nom)}$	--	--	--	0,7	--	--	A
Turn-on time to 90% $V_{OUT}$	$t_{on}$	--	60	100	--	50	100	$\mu\text{s}$
Turn-off time to 10% $V_{OUT}$	$t_{off}$	--	90	150	--	75	150	$\mu\text{s}$
Slew rate on 10 to 30% $V_{OUT}$	$dV/dt_{on}$	--	2	4	--	1	2	$\text{V}/\mu\text{s}$
Slew rate off 70 to 40% $V_{OUT}$	$-dV/dt_{off}$	--	2	4	--	1	2	$\text{V}/\mu\text{s}$

1) Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6 cm<sup>2</sup> (one layer, 70 $\mu\text{m}$  thick) copper area for  $V_{bb}$  connection. PCB is vertical without blown air..

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		min	typ	max	min	typ	max	

### Operating Parameters

Operating voltage	$V_{bb(\text{on})}$	12	--	35	12	--	45	V
Undervoltage shutdown	$V_{bb(\text{under})}$	7	--	10,5	7	--	10,5	V
Undervoltage restart	$V_{bb(\text{u.rst})}$	--	--	11	--	--	11	V
Undervoltage hysteresis	$\Delta V_{bb(\text{under})}$	--	0,4	--	--	--	0,5	V
Standby current $T_j = -40\dots85\text{ }^\circ\text{C}$ $T_j = 125\text{ }^\circ\text{C}^1)$	$I_{bb(\text{off})}$	--	10	20	--	10	25	$\mu\text{A}$
Operating current, $V_{IN} = \text{high}$	$I_{\text{GND}}$	0,5	1	1,5	--	1	1,6	mA
Leakage output current ( included in $I_{bb(\text{off})}$ ) $V_{IN} = 0\text{ V}$	$I_{L(\text{off})}$	0,4	--	1,2	--	3,5	10	$\mu\text{A}$

1) higher current due temperature sensor

### Electrical Characteristics

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Parameter and Conditions	Symbol	Values			Values			Unit
		Values			Values			
		min	typ	max	min	typ	max	
		at $T_j = 25\text{ }^\circ\text{C}$ , $V_{bb} = 24\text{ V}$			at $T_j = -40\dots125\text{ }^\circ\text{C}$ , $V_{bb} = 15\dots30\text{ V}$			

### Protection Functions

Initial peak short circuit current limit $T_j = -40\text{ }^\circ\text{C}$ $T_j = 25\text{ }^\circ\text{C}$ $T_j = 125\text{ }^\circ\text{C}$	$I_{L(\text{lim})}$	-- -- 0,7	-- 1,4 --	1,8 -- --	-- -- 0,7	-- 1,4 --	2,1 -- --	A
Output clamp (inductive load switch off) at $V_{\text{out}} = V_{bb} - V_{\text{ON(CL)}}$	$V_{\text{ON(CL)}}$	47	53	60	47	52	--	V
Overvoltage protection	$V_{bb(\text{AZ})}$	47	--	--	47	--	--	V
Thermal overload trip temperature	$T_{jt}$	135	150	--	135	--	--	$^\circ\text{C}$
Thermal hysteresis	$\Delta T_{jt}$	--	10	--	--	10	--	K

## Electrical Characteristics

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		at $T_j = 25\text{ }^\circ\text{C}$ , $V_{bb} = 24\text{ V}$			at $T_j = -40\dots125\text{ }^\circ\text{C}$ , $V_{bb} = 15\dots30\text{ V}$			
		min	typ	max	min	typ	max	

#### Input

Continuous input voltage	$V_{IN}$	-3,0	--	$V_{bb}$	-10 <sup>1)</sup>	--	$V_{bb}$	V
Input turn-on threshold voltage	$V_{IN(T+)}$	--	--	2,6	--	--	3,0	V
Input turn-off threshold voltage	$V_{IN(T-)}$	1,82	--	--	1,82	--	--	V
Input threshold hysteresis	$\Delta V_{IN(T)}$	--	0,1	--	--	0,2	--	V
Off state input current	$I_{IN(off)}$	20	--	--	20	--	--	$\mu\text{A}$
On state input current	$I_{IN(on)}$	--	--	110	--	--	110	$\mu\text{A}$
Input delay time at switch on $V_{bb}$	$t_{d(V_{bbon})}$	--	--	--	150	340	--	$\mu\text{s}$
Input resistance	$R_i$	--	--	--	1,5	3	5	$\text{k}\Omega$

#### Reverse Battery

Reverse battery <sup>1) 2)</sup>	$-V_{bb}$	--	--	--	--	--	45	V
Continuous reverse drain current	$I_s$	--	--	1	--	--	1	A
Drain source diode voltage	$-V_{ON}$	--	--	1,2	--	0,6	1,2	V

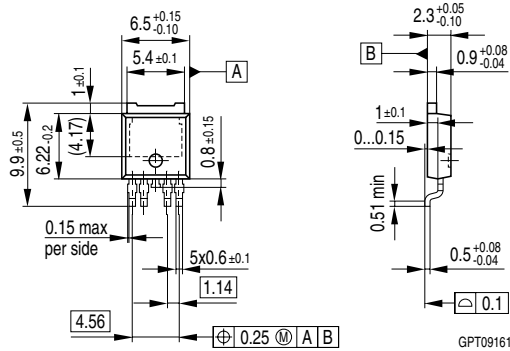
<sup>1)</sup> not subject to protection test, guaranteed by design

<sup>2)</sup> Requires 150  $\Omega$  resistor in GND connection. Reverse load current (through intrinsic drain-source diode) is normally limited by the connected load.

**Package:**

all dimensions in mm.

**D-Pak:**



All metal surfaces tin plated, except area of cut.

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